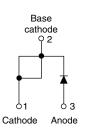


Schottky Rectifier, 8 A





PRODUCT SUMMARY	PRODUCT SUMMARY							
Package	TO-220AC							
I _{F(AV)}	8 A							
V _R	80 V, 100 V							
V _F at I _F	0.58 V							
I _{RM} max.	7 mA at 125 °C							
T _J max.	175 °C							
Diode variation	Single die							
E _{AS}	7.5 mJ							

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-8TQ...G Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	8	А						
V _{RRM}		100	V						
I _{FSM}	t _p = 5 μs sine	850	А						
V _F	8 A _{pk} , T _J = 125 °C	0.58	V						
TJ	Range	- 55 to 175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-8TQ080GPbF	VS-8TQ080G-N3	VS-8TQ100GPbF	VS-8TQ100G-N3	UNITS			
Maximum DC reverse voltage	V _R	80	80	100	100	v			
Maximum working peak reverse voltage	V _{RWM}	00	80	100	100				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 157 °C	8						
Maximum peak one cycle non-repetitive surge current	I =0.1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	230					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 0.50 \text{ A}, L = 60$	7.50	mJ					
Repetitive avalanche current	I _{AR}		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical						

Revision: 11-Oct-11

1



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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
Maximum forward voltage drop See fig. 1		8 A	T ₁ = 25 °C	0.72					
	V _{FM} ⁽¹⁾	16 A	1j=23 0	0.88	v				
	¥FM (*)	8 A	T ₁ = 125 °C	0.58					
		16 A	1j = 125 C	0.69					
Maximum reverse leakage curent	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.28					
See fig. 2	IRM (**	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	7	mA				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF				
Typical series inductance	L _S	Measured lead to lead 5 m	8	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs				

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANI	THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C						
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W						
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0,00						
Approximate weight			2	g						
Approximate weight			0.07	oz.						
minin	num		6 (5)	kgf ⋅ cm						
Mounting torque maxin	ıum		12 (10)	(lbf · in)						
Marking davias		Coop atula TO 2204C	8TQ	080G						
Marking device		Case style TO-220AC		100G						



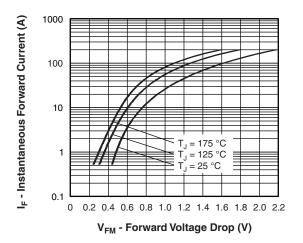


Fig. 1 - Maximum Forward Voltage Drop Characteristics

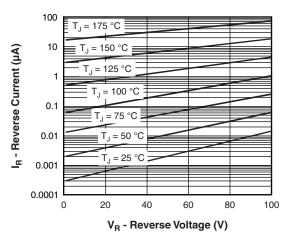


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

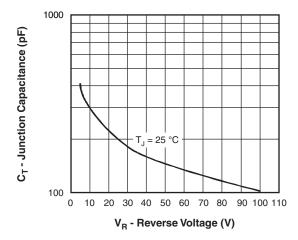
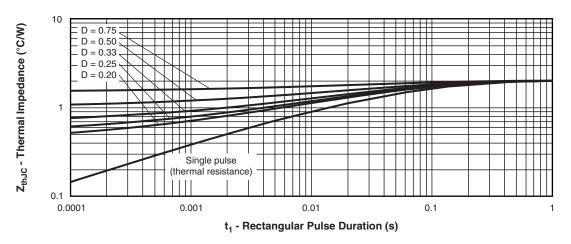
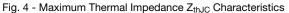


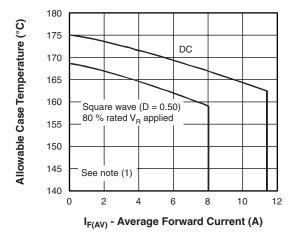
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

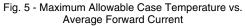


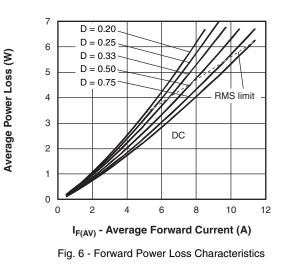


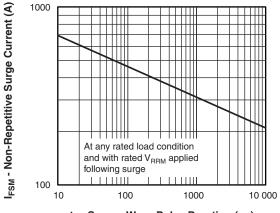
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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

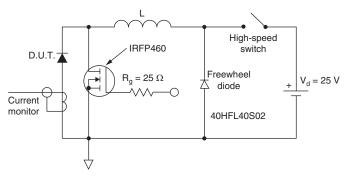


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

- Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 D)$; $I_R \text{ at } V_{R1}$ = 80 % rated V_R

Revision: 11-Oct-11

4

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ORDERING INFORMATION TABLE

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Device code	vs-	8	т	Q	100	G	PbF	
	1	2	3	4	5	6	7	
	 Vishay Semiconductors product Current rating (8 = 8 A) T = TO-220 							
	3 ⁻ 4 ⁻	Q =	Schottk	ky "Q" se	eries			
	5 -	- Volt	age rati	ng (100	= 100 V	')		
	6 -	G =	Schottk	ky gener	ation			
	7 -	Env	ironmer	ntal digit				

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8TQ080GPbF	50	1000	Antistatic plastic tube						
VS-8TQ080G-N3	50	1000	Antistatic plastic tube						
VS-8TQ100GPbF	50	1000	Antistatic plastic tube						
VS-8TQ100G-N3	50	1000	Antistatic plastic tube						

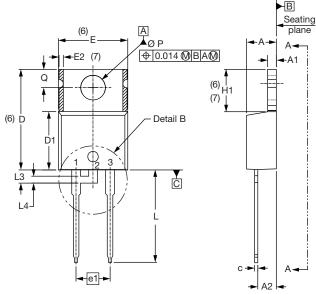
LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224				
	TO-220AC -N3	www.vishay.com/doc?95068				
SPICE model		www.vishay.com/doc?95291				

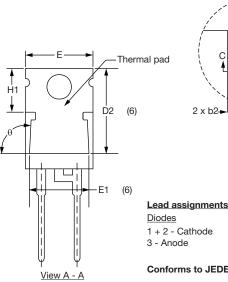


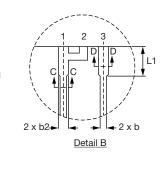
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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